

TANDO 700

Technical Data



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1 Technical data

1.1 Care and cleaning

TANDO 700, MCU1 and SHT1 do not require any special maintenance or care. Clean the devices from time to time or as necessary.

WARNING



Death or severe injury caused by high voltage or current possible

- ▶ Switch off the high voltage before disconnecting the system.
- ▶ Always observe the five safety rules (see 1.2.2 "Safety rules" on page 6).

To clean *TANDO 700*, use a cloth dampened with isopropanol alcohol or water.

1.2 *TANDO 700* acquisition unit

1.2.1 Specification standard system

Table 1-1: Specification of the standard system

Value	Condition	Accuracy ¹⁾
Dissipation factor / Power factor	Auto mode $5 \mu\text{A} \leq I_{IN} \leq 1 \text{ A}$	$0.1 \% \text{ rdg.} + 1 \times 10^{-4}$
Capacitance (DUT)	Auto mode $5 \mu\text{A} \leq I_{IN} \leq 1 \text{ A}$	$0.1 \% \text{ rdg.} + 0.1 \text{ pF}$
Current	Auto mode $5 \mu\text{A} \leq I_{IN} \leq 1 \text{ A}$	$0.1 \% \text{ rdg.} + 0.1 \text{ nA}$
Voltage	$10 \text{ pF} \leq C_{Ref} \leq 10 \text{ nF}$	$0.5 \% \text{ rdg.} + 1 \text{ V}$
Frequency	$5 \text{ Hz} \dots 400 \text{ Hz}$	$0.0025 \% \text{ rdg.}$

1) The accuracies are given without errors depending on C_{Ref} , input combination and parasitic capacitances (see Table 1-3: "Additional specifications" on page 5). The specified accuracies are valid for the frequency of the test voltage at 50/60 Hz, SINAD of power source < 12 dB and a temperature range of $23^\circ\text{C} \pm 5^\circ\text{C}$.

Note: Calibration of the *TANDO 700* is recommended every 2 years.

1.2.2 Specification advanced system

Table 1-2: Specification of the advanced system

Value	Condition	Guaranteed accuracy ¹⁾	Typical accuracy ¹⁾
Dissipation factor/ Power factor	Auto mode $5 \mu\text{A} \leq I_{IN} \leq 1 \text{ A}$	$0.1 \% \text{ rdg.} + 2 \times 10^{-5}$	$< 5 \times 10^{-6}$
Capacitance (DUT)	Auto mode $5 \mu\text{A} \leq I_{IN} \leq 1 \text{ A}$	$0.05 \% \text{ rdg.} + 0.05 \text{ pF}$	0.005%
Current	Auto mode $5 \mu\text{A} \leq I_{IN} \leq 1 \text{ A}$	$0.05 \% \text{ rdg.} + 0.05 \text{ nA}$	$< 0.02 \%$
Voltage	$10 \text{ pF} \leq C_{Ref} \leq 10 \text{ nF}$	$0.2 \% \text{ rdg.} + 1 \text{ V}$	$< 0.02 \%$
Frequency	$5 \text{ Hz} \dots 400 \text{ Hz}$	$0.001 \% \text{ rdg.}$	$< 0.001 \% \text{ rdg.}$

1) The accuracies are given without errors depending on C_{Ref} , input combination and parasitic capacitances (see Table 1-3: "Additional specifications" on page 5). The specified accuracies are valid for the frequency of the test voltage at 50/60 Hz, SINAD of power source < 12 dB and a temperature range of $23^\circ\text{C} \pm 5^\circ\text{C}$.

Note: Calibration of the *TANDO 700* is recommended every 2 years.

1.2.3 Additional specifications

Accuracies (see Table 1-1: on page 3 and Table 1-2: on page 4) are not influenced if the occurring parasitic capacitances are within the given values:

Table 1-3: Additional specifications

Measuring range	Max. parasitic capacitances
1.2 mA	750 pF
200 mA	250 pF
1 A	2.3 nF
SHT1 version A: 4 A	25 nF
SHT1 version B: 15 A	250 nF
SHT1 version C: 28 A	850 nF

The influence of the parasitic capacitance on the dissipation factor is calculated according to the formula:
 $\text{Err tan-}\delta \text{ (parasitic)} = \omega R_i C_{\text{parasitic}}$

Table 1-4: Additional error depending on test frequency (error = 0 at 55 Hz)

	ΔC	$\Delta \tan-\delta$
Typical coefficient	$4 \times 10^{-6} \frac{\%}{Hz}$	$2.5 \times 10^{-6} \frac{\%}{Hz}$

Table 1-5: Additional error depending on ambient temperature (error = 0 at 25 °C)

	ΔC	$\Delta \tan-\delta$
Typical coefficient	$1 \times 10^{-4} \frac{\%}{^{\circ}C}$	$3 \times 10^{-7} \frac{\%}{^{\circ}C}$

Table 1-6: Additional error depending on temperature difference between sensors (error = 0 at 0 K)

	ΔC	$\Delta \tan-\delta$
Typical coefficient	$1.5 \times 10^{-4} \frac{\%}{K}$	$8 \times 10^{-6} \frac{\%}{K}$

1.2.4 Resolution / display / measuring range

Table 1-7: Resolution / display / measuring range

Value	Measuring range	Standard system	Advanced system
Phase angle	- π ... π	0.1×10^{-4}	1×10^{-8}
Capacitance (DUT)	See Table 1-8: "System data" on page 6	1 pF 5 digits	0.01 pF 6 digits
Current	1 nA ... 1 A	0.1 pA 5 digits	0.1 pA 6 digits
Voltage	0 V ... 1 MV	1 μ V 5 digits	1 μ V 6 digits
Frequency	5 Hz ... 400 Hz	0.01 mHz 5 digits	0.01 mHz 6 digits

1.2.5 System data

Table 1-8: System data

Direct input:		
1.2 mA	Impedance	$17 \Omega (\pm 15\%)$
	Current range	0.5 μ A ... 1.2 mA
	Capacitance (DUT) ²⁾ range	$C_{min}^1)$... 3 nF
Internal shunt input:		
200 mA input	Impedance	$50 \Omega (\pm 2\%)$
	Current range	1 mA ... 200 mA
	Capacitance (DUT) ²⁾ range	$C_{min}^1)$... 30 nF
1 A input	Impedance	$5.4 \Omega (\pm 2\%)$
	Current range	10 mA ... 1 A
	Capacitance (DUT) ²⁾ range	$C_{min}^1)$... 300 nF
Connection to MCU1:		
Fiber-optic	Wave length	1300 nm
	Mode	Multimode 50 / 125 μ m
	Fiber length	Up to 2 km
Others:		
Data acquisition	Sampling rate	7.812 kS/s
Reference capacitor	Capacitance range	10 pF ... 10 nF

1) $C_{min} = I_{min} / (\omega U_{test})$

2) Without external shunt

1.2.6 Power data

Table 1-9: Power data

Parameter	Value
Supply voltage (Power input)	9 V ... 24 V DC, 24 W
External power supply unit FW7362M/18/OM	Input range: 100 V ... 240 V 50 Hz ... 60 Hz 10 °C ... 55 °C ¹⁾
Power consumption	< 100 mW active < 1 mW standby < 15 W charging
Internal battery pack	Rechargeable lithium battery 3.7 V / 11.6 Ah
Battery exchange	Every 4 years
Internal battery charge period	Minimum 21 days
Typical charging duration	Maximum 4 h (7 h charging by RBP1)

1) For charging, note that the temperature limits of the internal battery have to be considered.

1.2.7 Mechanical data

Table 1-10: Mechanical data

Characteristic	Rating
Dimensions (W x D x H)	115 mm x 175 mm x 55 mm
Weight	0.92 kg
Connections	Front: Two ST connectors for fiber-optic network One 4 pin DC input socket, LEMO FFA Rear: Two 4 mm banana red/black plug One 4 pin shunt socket, LEMO FGG
Indicator	Bar graph display with status indicator

1.2.8 Environmental conditions

Table 1-11: Environmental conditions

Characteristic	Rating
Operating temperature	-10 °C ... +50 °C
Storage temperature	-20 °C ... +60 °C
Long term storage temperature (max.1 year)	-20 °C ... +30 °C
Charging temperature	0 °C ... +40 °C
Humidity	5 % ... 85 % (non-condensing)
Max. operating altitude	4000 m

1.2.9 Standards

Table 1-12:

EMC, safety	
EMC	IEC/EN 61326-1 (industrial electromagnetic environment) FCC subpart B of part 15, class A
Safety	IEC/EN/UL 61010-1, IEC/EN/UL 61010-2-030 IEC 62133, UL 2054, UN 38.3
Other	
Shock	IEC/EN 60068-2-27 (15 g/11 ms (150 m/s ² /11 ms), half-sinusoid, 3 shocks in each axis)
Vibration	IEC/EN 60068-2-6 (frequency range 10 Hz ... 150 Hz, acceleration 2 g continuous (20 m/s ² /65 ft/s ²), 10 cycles per axis)
Humidity	IEC/EN 60068-2-78 (5%...95% relative humidity, no condensation, tested at 40 °C/104 °F for 48 hours)
Ingress protection (connectors mated)	IEC/EN 60529 IP 4x



1.3 **MCU1 multi-device control unit**

1.3.1 **Power data**

Table 1-13: Power data

Parameter	Value
Supply voltage (Power input)	USB 2.0, bus powered
Power consumption	< 2.5 W

1.3.2 **Mechanical data**

Table 1-14: Mechanical data

Characteristic	Rating
Dimensions (W x D x H)	115 mm x 175 mm x 38 mm
Weight	0.52 kg
Connections	<p>Front: 1 x USB 2.0</p> <p>Rear: 6 x ST connectors for fiber-optic network</p>
Indicator	1 x LED, USB connection/error indicator
Additional features	1 x light sensitive trigger, 50 Hz ... 60Hz

1.3.3 **Environmental conditions**

Table 1-15: Environmental conditions

Characteristic	Rating
Operating temperature	-20 °C ... +65 °C
Storage temperature	-40 °C ... +85 °C
Humidity	5 % ... 85 % (non-condensing)
Max. operating altitude	4000 m

1.4 SHT1 external shunt

1.4.1 System data

Table 1-16: System data

Parameter	Value		
Maximum current	4 A	15 A	28 A
Minimum current with TANDO 700 system	100 mA	1 A	3 A
Typical nominal resistance ¹⁾	500 mΩ	50 mΩ	15 mΩ
Typical temperature coefficient	2 ppm	2 ppm	2 ppm
Initial resistance accuracy	±0.04 %		
Long term resistance deviation (1000 full load cycle / 2 years)	< ±0.15 %		
Absolute phase deviation	$\tan-\delta < 2 \times 10^{-5}$		

1) This indicates the deviation from the resistance value measured during SHT1 calibration, which is stored in the SHT1 and will be used by the TANDO 700 software. The initial resistance value may differ up to 1 % from the mentioned typical nominal value.

1.4.2 Mechanical data

Table 1-17: Mechanical data

Characteristic	Rating
Dimensions (W x D x H)	120 mm x 175 mm x 45 mm
Weight	0.68 kg
Connections	<p>Front: One 4 pin shunt socket, LEMO FGG</p> <p>Rear: Two 4 mm banana red/black plug</p>

1.4.3 Environmental conditions

Table 1-18: Environmental conditions

Characteristic	Rating
Operating temperature	-20 °C ... +60 °C
Storage temperature	-20 °C ... +60 °C
Humidity	5 % ... 85 % (non-condensing)
Max. operating altitude	4000 m